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2EDS8265HXUMA2

10.00

Data Sheet

Fast, robust, dual-channel, reinforced isolated MOSFET gate drivers with accurate and stable timing

Manufacturers	Infineon Technologies Corporation		
Package/Case	PG-DSO-16	2	
Product Type	Integrated Circuits (ICs)	ARRANGO .	*
RoHS			
Lifecycle		Images are for reference or	nly
Please submit RFQ f	for 2EDS8265HXUMA2 or <u>Email to us: sales@ovaga.com</u> We will contact you in	12 hours.	<u>RFQ</u>

General Description

The EiceDRIVERTM 2EDS8265H and 2EDS8165H are reinforced isolated gate drivers for secondary-side control over the mandatory safe isolation barrier in SMPS. The 2EDS8265H strong 4A/8A source/sink dual-channel gate driver comes with a very high 150V/ns CMTI (Common Mode Transient Immunity) for robust operation with fast CoolMOSTM and high power switching noise environment.

The very fast propagation delay of 37ns is provided with low variation over temperature and production which enables the power system design to achieve higher efficiency through very tight timing control across the safety isolation barrier. The 2EDS8165H with 1A/2A is available for smaller MOSFETs or PWM signal/data decoupling for very high power designs working with local boost drivers. Safety certificates in accordance with UL1577, VDE0884-10, IEC62368 and IEC60950 will be provided with these devices. The 2EDFS8xx5H parts come in wide-body 300 mil DSO16 packages.

Features

Application

Fast switching with accurate timing	Telecom DC-DC
Optimized for area and system BOM	Server
Robust against switching noise	Industrial SMPS
Output- to-output channel isolation	UPS
Input-to-output channel isolation	Battery
Efficiency gain and lower losses	EV-Charging
Improved thermal behavior at smaller form factor	Smart Grid
Protection and safe operation	
Flexible configurations	

Regulatory safety

Enabling higher system efficiency and higher power density designs

Improving long term competitive cost position, integration and mass manufacturability

Extending end-product lifetime by improving safe operation of power switches in normal and abnormal field (grid) conditions

Lower EMI by ground isolation, driver proximity to MOSFETs or when using 4-pin Kelvin source MOSFETs

Simplified safety approval through component (VDE884-x, UL1577 and system (IEC60950, IEC62368) certificates

Related Products



BTS442E2-E3062A

SAK-C504-2E24M

Infineon Technologies Corporation TO263



Infineon Technologies Corporation MQFP-44



BTS50452EKA Infineon Technologies Corporation SOP-14









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Infineon Technologies Corporation **BGA388**



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Infineon Technologies Corporation SOP-14

BSP452E6327



BTT6030-2ERA

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